

NGB15T65M3DFP650 V, 15 A trench field-stop IGBT with full rated silicon diodeRev. 1 — 6 June 2025Product data sheet **Product data sheet** 

### 1. General description

NGB15T65M3DFP is a robust Insulated-Gate Bipolar Transistor (IGBT) featuring third-generation technology. It combines carrier stored trench-gate and field-stop (FS) structures. NGB15T65M3DFP is rated to 175 °C with optimized IGBT turn-off losses, and has a short circuit withstand time of 5 µs. This hard-switching 650 V, 15 A IGBT is optimized for high-voltage, high-frequency industrial power inverter applications and servo motor drive applications.

### 2. Features

- Device current is rated at 15 A
- Low conduction and switching losses
- Stable and tight parameters for easy parallel operation
- Maximum junction temperature 175 °C •
- Fully rated and fast reverse recovery diode
- 5 µs short circuit withstand time

### 3. Applications

- Motor drives for industrial and consumer appliances
  - Servo motors operating between 5-20 kW (up to 20 kHz) for robotics, elevators, operating • grippers, in-line manufacturing, etc.
- Power converter applications, such as uninterruptible power supply (UPS)
- Induction heating
- Welding

### 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CES</sub>	collector-emitter voltage	T <sub>vj</sub> = 25 °C	-	650	V
T <sub>vj</sub>	operating junction temperature		-40	175	°C
t <sub>sc</sub>	short circuit withstand time	$V_{GE}$ = 15 V; $V_{CC}$ = 400 V; $T_{vj} \le$ 150 °C	-	5.0	μs



# 5. Pinning information

Table 2. P	inning inforr	nation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	4	
2	С	collector		С
3	E	emitter		
4	C	mounting base; connected to collector		G E aaa-036518

# 6. Ordering information

#### **Table 3. Ordering information**

Type number	Package				
	Name	Description	Version		
NGB15T65M3DFP	D2PAK	Plastic single-ended surface-mounted package (D2PAK); 3 terminals (one lead cropped)	<u>SOT404B-1</u>		

### 7. Limiting values

#### Table 4. Limiting values

Symbol	Parameter		Conditions	Min	Max	Unit
	1		IGBT	1		
V <sub>CES</sub>	collector-emitter voltage		T <sub>vj</sub> = 25 °C	-	650	V
I <sub>C</sub>	collector current	[1]	T <sub>c</sub> = 25 °C	-	33	А
			T <sub>c</sub> = 100 °C	-	23	А
I <sub>CRM</sub>	repetitive peak collector current	[2]		-	45	А
t <sub>sc</sub>	short circuit withstand time	[3]	V <sub>GE</sub> = 15 V; V <sub>CC</sub> = 400 V; T <sub>vj</sub> ≤150 °C	-	5.0	μs
$V_{GE}$	gate-emitter voltage			-20	20	V
P <sub>tot</sub>	total power dissipation		T <sub>c</sub> = 25 °C	-	127	W
			T <sub>c</sub> = 100 °C	-	64	W
T <sub>vj</sub>	operating junction temperature			-40	175	°C
T <sub>stg</sub>	storage temperature			-55	150	°C
T <sub>solder</sub>	soldering temperature			-	260	°C
			Diode			
I <sub>F</sub>	diode forward current	[1]	T <sub>c</sub> = 25 °C	-	33	А
			T <sub>c</sub> = 100 °C	-	21	А
I <sub>FRM</sub>	repetitive peak forward current	[2]		-	45	А

Value is limited by internal bonding wire and  $T_{vj(max)}$ . [1]

[2]

Time duration is limited by  $T_{vj(max)}$ . Short circuit cycles  $\leq$  1000, time between tests  $\geq$  1 s. [3]

# 8. Thermal characteristics

Table 5. Therm	nal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
R <sub>th(j-c)</sub>	thermal resistance from junction to case	IGBT	-	1.00	1.18	K/W
		diode	-	1.71	2.02	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	minimum footprint on PCB	-	-	65	K/W

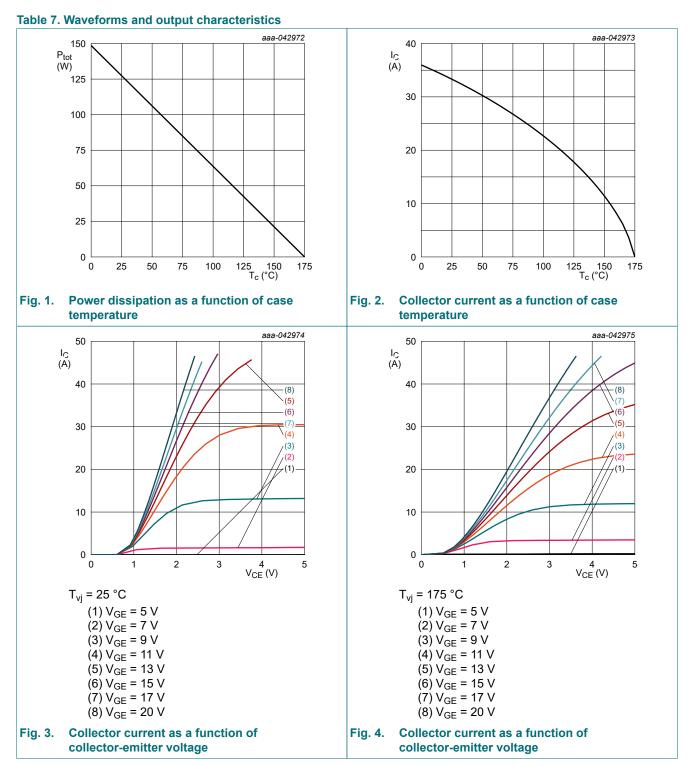
# 9. Electrical characteristics

#### Table 6. Characteristics

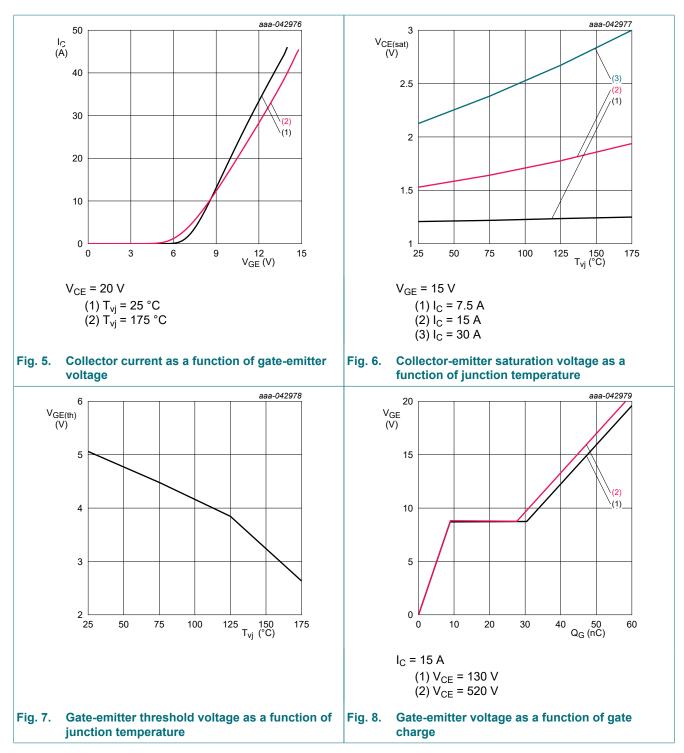
All values at  $T_{vj}$  = 25 °C, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
		Static characteristics				
V <sub>(BR)CES</sub>	collector-emitter breakdown voltage	$V_{GE} = 0 \text{ V}; I_{C} = 0.2 \text{ mA}$	650	-	-	V
V <sub>CEsat</sub>	collector-emitter saturation	V <sub>GE</sub> = 15 V; I <sub>C</sub> = 15 A; T <sub>vj</sub> = 25 °C	-	1.53	1.7	V
	voltage	V <sub>GE</sub> = 15 V; I <sub>C</sub> = 15 A; T <sub>vj</sub> = 175 °C	-	1.94	-	V
V <sub>F</sub>	diode forward voltage	V <sub>GE</sub> = 0 V; I <sub>F</sub> = 15 A; T <sub>vj</sub> = 25 °C	-	1.57	1.9	V
		V <sub>GE</sub> = 0 V; I <sub>F</sub> = 15 A; T <sub>vj</sub> = 175 °C	-	1.29	-	V
V <sub>GE(th)</sub>	gate-emitter threshold voltage	I <sub>C</sub> = 0.15 mA; V <sub>CE</sub> = V <sub>GE</sub> ; T <sub>vj</sub> = 25 °C	4.3	5.0	5.7	V
I <sub>CES</sub>	zero gate voltage collector current	V <sub>CE</sub> = 650 V; V <sub>GE</sub> = 0 V; T <sub>vj</sub> = 25 °C	-	3	-	nA
		V <sub>CE</sub> = 650 V; V <sub>GE</sub> = 0 V; T <sub>vj</sub> = 175 °C	-	0.2	-	mA
I <sub>GES</sub>	gate-emitter leakage current	V <sub>CE</sub> = 0 V; V <sub>GE</sub> = 20 V	-	-	100	nA
9 <sub>fs</sub>	transconductance	V <sub>CE</sub> = 20 V; I <sub>C</sub> = 15 A; T <sub>vj</sub> = 25 °C	-	7.0	-	S
r <sub>g</sub>	internal gate resistor		-	2.9	-	Ω
		Dynamic characteristics				
C <sub>ies</sub>	input capacitance	V <sub>CE</sub> = 25 V; V <sub>GE</sub> = 0 V; f = 1 MHz	-	1136	-	pF
C <sub>oes</sub>	output capacitance		-	42	-	pF
C <sub>res</sub>	reverse transfer capacitance		-	12	-	pF
Q <sub>G</sub>	gate charge	V <sub>CC</sub> = 520 V; I <sub>C</sub> = 15 A; V <sub>GE</sub> = 15 V	-	45	-	nC
L <sub>sCE</sub>	internal stray inductance		-	6.2	-	nH
I <sub>C(sc)</sub>	short circuit collector current	$V_{GE}$ = 15 V; $V_{CC}$ = 400 V; $t_{sc} \le 5 \ \mu s$ ; $T_{vj} \le 150 \ ^{\circ}C$	-	77	-	Α

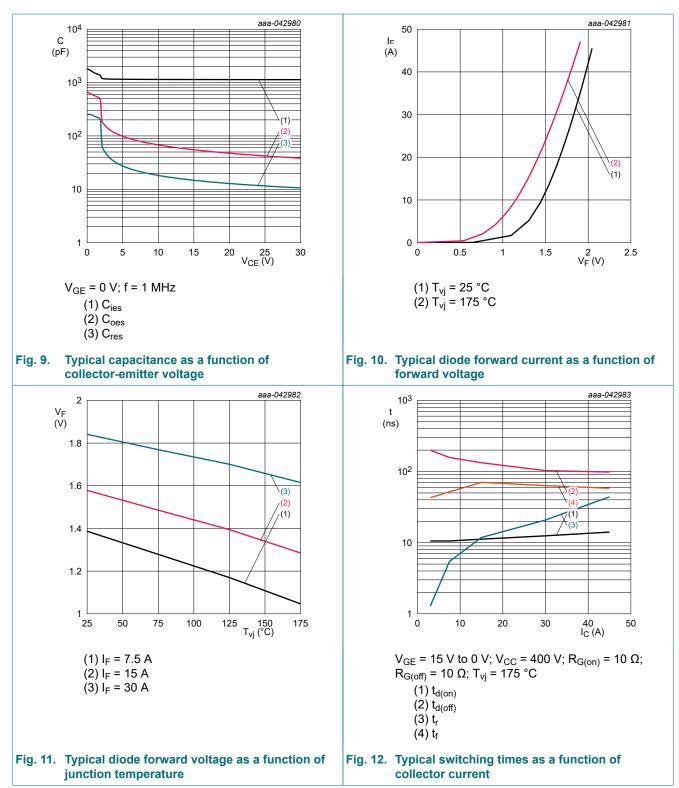
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
	IGB	switching characteristics, indu	ctive load				
t <sub>d(on)</sub>	turn-on delay time	V <sub>GE</sub> = 15/0 V; V <sub>CC</sub> = 400 V;	T <sub>vj</sub> = 25 °C	-	12	-	ns
		$I_{C}$ = 15 A; R <sub>G(on)</sub> = 10 Ω; R <sub>G(off)</sub> = 10 Ω;	T <sub>vj</sub> = 175 °C	-	11	-	ns
t <sub>r</sub>	rise time	see Fig. 27 and Fig. 28	T <sub>vj</sub> = 25 °C	-	8	-	ns
			T <sub>vj</sub> = 175 °C	-	12	-	ns
t <sub>d(off)</sub> turn-off delay time	turn-off delay time		T <sub>vj</sub> = 25 °C	-	88	-	ns
			T <sub>vj</sub> = 175 °C	-	133	-	ns
t <sub>f</sub>	fall time		T <sub>vj</sub> = 25 °C	-	46	-	ns
			T <sub>vj</sub> = 175 °C	-	70	-	ns
Eon	turn-on switching energy loss		T <sub>vj</sub> = 25 °C	-	0.33	-	mJ
			T <sub>vj</sub> = 175 °C	-	0.72	-	mJ
E <sub>off</sub>	turn-off switching energy loss		T <sub>vj</sub> = 25 °C	-	0.19	-	mJ
			T <sub>vj</sub> = 175 °C	-	0.33	-	mJ
E <sub>ts</sub> total switching energy lo	total switching energy loss		T <sub>vj</sub> = 25 °C	-	0.52	-	mJ
			T <sub>vj</sub> = 175 °C	-	1.06	-	mJ
	Diod	e switching characteristics, indu	ctive load				
t <sub>rr</sub>	reverse recovery time	V <sub>R</sub> = 400 V; I <sub>F</sub> = 15 A;	T <sub>vj</sub> = 25 °C	-	88	-	ns
		di <sub>F</sub> /dt = 500 A/µs; see <u>Fig. 26</u>	T <sub>vj</sub> = 175 °C	-	173	-	ns
Q <sub>rr</sub>	reverse recovery charge		T <sub>vj</sub> = 25 °C	-	459	-	nC
			T <sub>vj</sub> = 175 °C	-	1604	-	nC
l <sub>rrm</sub>	peak reverse recovery current		T <sub>vj</sub> = 25 °C	-	14	-	А
			T <sub>vj</sub> = 175 °C	-	22	-	Α
E <sub>rec</sub>	reverse recovery energy loss		T <sub>vj</sub> = 25 °C	-	0.06	-	mJ
			T <sub>vj</sub> = 175 °C	-	0.27	-	mJ
di <sub>rrf</sub> /dt	fall rate of reverse recovery	]	T <sub>vj</sub> = 25 °C	-	276	-	A/µs
	current		T <sub>vj</sub> = 175 °C	-	239	-	A/µs

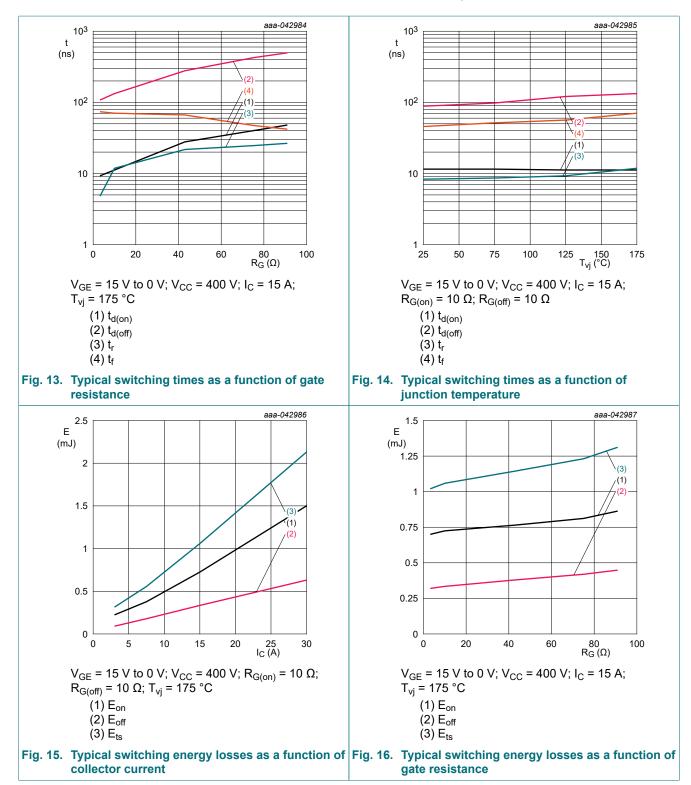


### 9.1. Characteristic diagrams





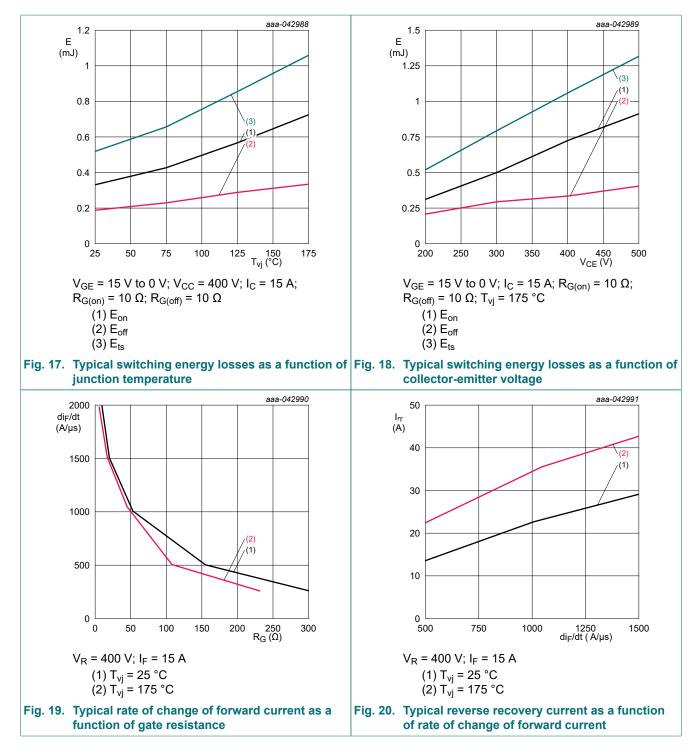


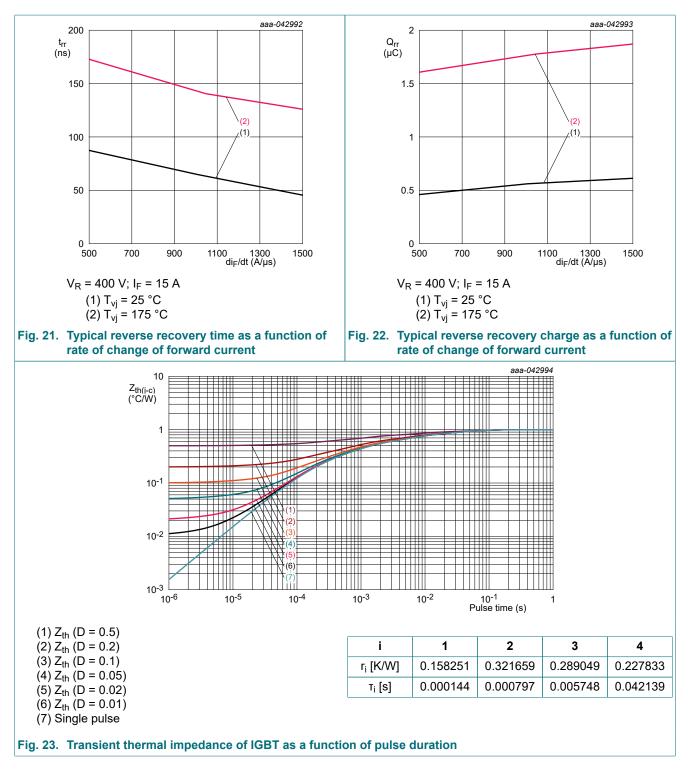


#### 650 V, 15 A trench field-stop IGBT with full rated silicon diode

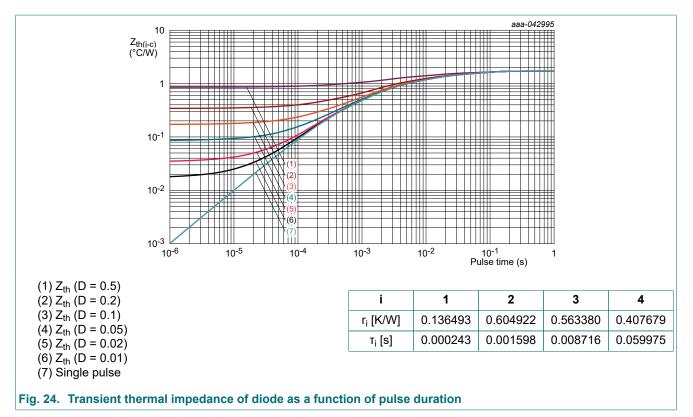
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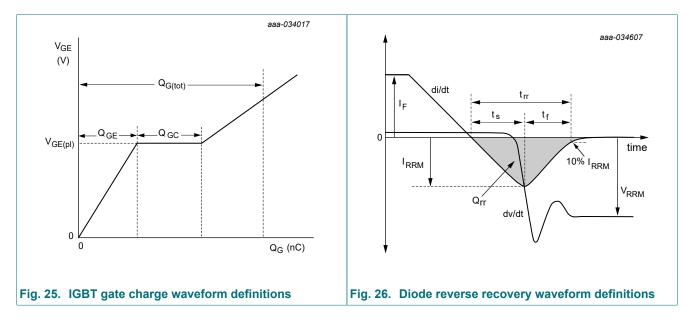


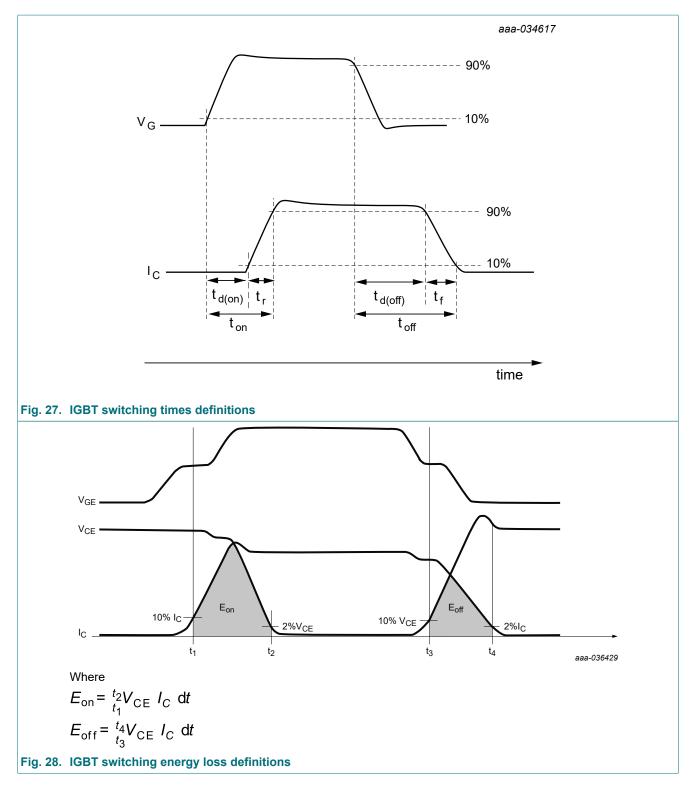


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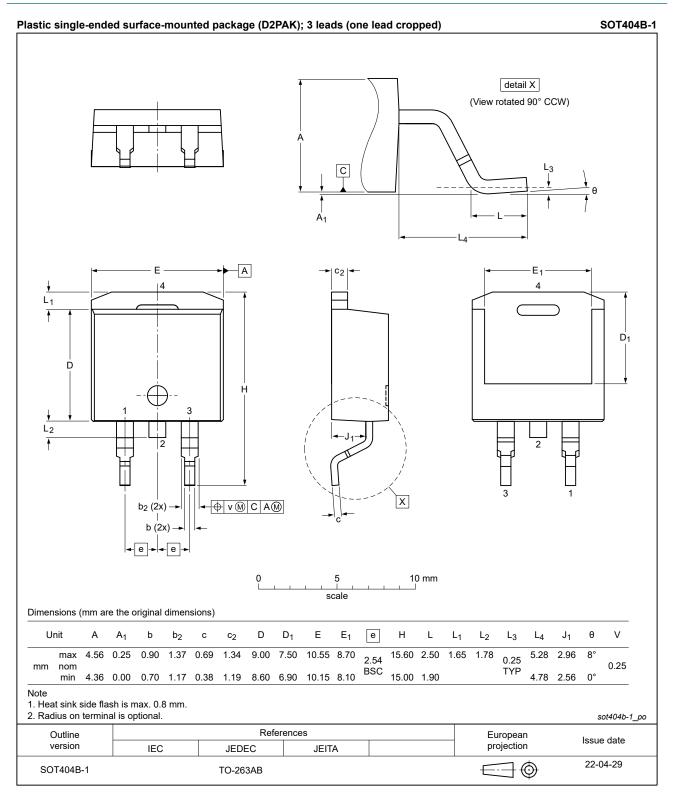


### 9.2. Waveform definitions





# 10. Package outline



#### Fig. 29. Package outline D2PAK (SOT404B-1)

# **11. Revision history**

Table 8. Revision history				
Document ID	Release date	Data sheet status	Change notice	Supersedes
NGB15T65M3DFP v. 1	June 6, 2025	Product data sheet	-	-

# 12. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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